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CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8) Applicant(s): Clevenger et al.			Docket No. YOR920010246US2	
Application No. 10/751,205	Filing Date January 2, 2004	Examiner Unknown	Group Art Unit	
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## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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In re divisional patent application of

Clevenger et al.

Serial No.: 10/751,205

Group Art Unit: 2878

Filed: January 2, 2004

Examiner: Unknown

For:

THREE-DIMENSIONAL ISLAND PIXEL PHOTO-SENSOR

Commissioner of Patents PO BOX 1450 Alexandria, VA 22313-1450

## RESPONSE TO NOTICE OF NON-COMPLIANT AMENDMENT

Sir:

In response to the Notice of Non-Compliant Amendment dated 10/22/04, a complete list of all the claims pending in the application is provided herewith.

Claims 1-19 (Cancelled).

- (Original) A method of forming an island photodiode comprising:
  - forming a core in a substrate;
  - forming trenches in said substrate adjacent said core;
  - forming light sensing sidewalls along said trenches; and
  - forming logic circuitry above said core.
- 21. (Original) The method in claim 20, wherein said sidewalls are perpendicular to a surface of said photodiode that receives incident light.
- 22. (Original) The method in claim 20, wherein said forming of said light sensing sidewalls comprises doping sidewalls of said trench to form a junction region between said